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NCE15GD135P

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1350V, 15A, Trench NPT IGBT

Features

- Trench NPT(Non Punch Through) IGBT
- High speed switching
- Low saturation voltage: V_{CE(sat)}=2.0V@I_C=15A
- High input impedance

Applications

- Inductive heating, Microwave oven, Inverter, UPS, etc.
- Soft switching applications

General Description

Using advanced Trench NPT technology, NCE's 1350V IGBTs offers superior conduction and switching performances, and easy parallel operation with exceptional avalanche ruggedness. This device is designed for soft switching applications.

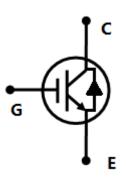
Absolute Maximum Ratings

Symbol	Description	Ratings	Units
V _{CES}	Collector to Emitter Voltage	1350	V
V_{GES}	Gate to Emitter Voltage	+/-30	V
Ι _C	Continuous Collector Current @T _C =25°C	30	Α
	Continuous Collector Current @T _C =100°C	15	Α
I _{CM} (1)	Pulsed Collector Current	45	Α
I _F	Diode Continuous Forward Current @T _C =100°C	15	
I _{FM}	Diode Maximum Forward Current	90	Α
P _D	Maximum Power Dissipation @T _c =25°C	220	W
	Maximum Power Dissipation @T _c =100°C	88	W
TJ	Operating Junction Temperature	-55 to +150	°C
T _{stg}	Storage Temperature Range	-55 to +150	°C
	Maximum Lead Temp. for soldering Purposes, 1/8" from		
TL	case for 5seconds	300	°C

Notes:

1. Repetitive rating, Pulse width limited by max. junction temperature







Thermal Characteristics

Symbol	Parameter	Тур.	Max.	Units
R _{JC}	Thermal Resistance, Junction to Case	-	0.57	°C/W
R _{JA}	Thermal Resistance, Junction to Ambient	-	40	°C/W

Electrical Characteristics of the IGBT $_{T_{c}=25^{\circ}C}$

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Units
Off Char	acteristics					
BV_{CES}	Collector to Emitter	V _{GE} =0V, Ic=1mA	1350	-	_	V
	Breakdown Voltage		1000	-		v
I _{CES}	Collector Cut-Off Current	V_{CE} = V_{CES} , V_{GE} =0V	-	-	1	mA
I _{GES}	G-E Leakage Current	V_{GE} = V_{GES} , V_{CE} =0 V	-	-	+/-250	nA
On Char	acteristics					
$V_{\text{GE(th)}}$	G-E Threshold Voltage	I_C =15mA, V_{CE} = V_{GE}	4.0	5.5	7.0	V
V _{CE(sat)}	Collector to Emitter Saturation	I _C =15A, V _{GE} =15V T _C =25°C	-	2	2.5	V
	Voltage	I _C =15A, V _{GE} =15V T _C =125°C	-	2.15	-	V
Dynamic	Characteristics					
Cies	Input Capacitance		-	2350	-	pF
C _{oes}	Output Capacitance	V _{CE} =30V, V _{GE} =0V,	-	70	-	pF
C _{res}	Reverse Transfer	f=1MHz	-		_	pF
	Capacitance			45		F.
Switchin	g Characteristics	I	_		1	
t _{d(on)}	Turn-On Delay Time		-	33	-	ns
t _r	Rise Time	V _{CC} =600V,I _C =15A,	-	80	-	ns
$t_{d(off)}$	Turn-Off Delay Time	R _G =10Ώ,V _{GE} =15V,	-	160	-	ns
t _f	Fall Time	Resistive Load,	-	255	330	ns
Eon	Turn-On Switching Loss	T _c =25°C	-	0.3	-	mJ
E _{off}	Turn-Off Switching Loss		-	0.58	0.74	mJ
E _{ts}	Total Switching Loss		-	0.88	-	mJ
t _{d(on)}	Turn-On Delay Time		-	30	-	ns
tr	Rise Time		-	115	-	ns
$t_{d(off)}$	Turn-Off Delay Time	$V_{\rm CC}$ =600V,I _C =15A,	-	170	-	ns
t _f	Fall Time	R_{G} =10 Ω, V_{GE} =15V,	-	390	-	ns
Eon	Turn-On Switching Loss	Resistive Load,	-	0.38	-	mJ
E _{off}	Turn-Off Switching Loss	T _C =125°C	-	0.89	-	mJ
E _{ts}	Total Switching Loss		-	1.27	-	mJ
Qg	Total Gate Charge		-	100	-	nC
Q _{ge}	Gate to Emitter Charge	V_{CC} =600V,I _C =15A,	-	19	-	nC
Q _{gc}	Gate to Collector Charge	V _{GE} =15V	-	45	-	nC



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Electrical Characteristics of Diode $T_{c=25^{\circ}C}$

Symbol	Parameter	Test Conditions		Min.	Тур.	Max.	Units
V _{FM}		I _F =15A	25°C		1.4	1.8	V
	Diode Forward Voltage		125°C		1.42		V
t _{rr}	Diode Reverse Recovery		25°C		575		ns
	Time		125°C		577		ns
I _{rr}	Diode Peak Reverse	I _F =15A,	25°C		30		Α
	Recovery Current	dl/dt=200A/us	125°C		37		A
Q _{rr}	Diode Reverse Recovery		25°C		8.7		uC
	Charge		125°C		10.7		uC



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Typical Performance Characteristics

Figure 1. Typical Output Characteristics

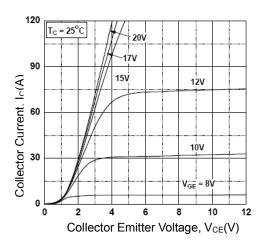


Figure 3. Saturation Voltage vs. Case Temperature at Variant Current Level

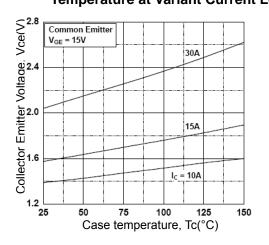


Figure 5. Saturation Voltage vs. V_{GE}

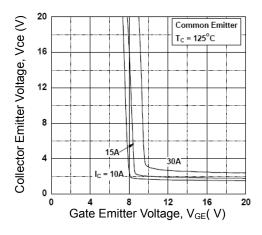


Figure 2. Typical Saturation Voltage

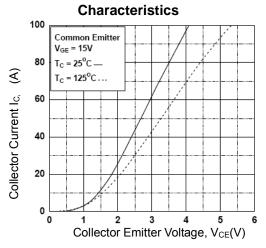


Figure 4. Saturation Voltage vs. V_{GE}

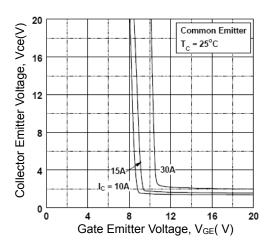
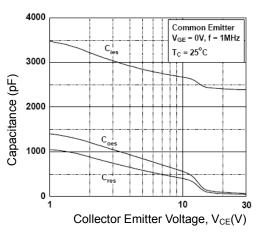


Figure 6. Capacitance Characteristics



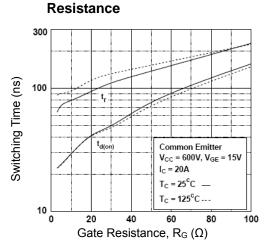




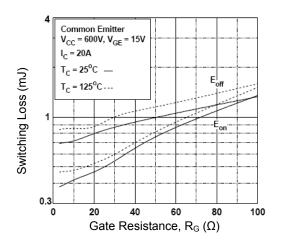
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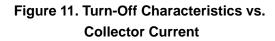
Typical Performance Characteristics (Continued)

Figure 7. Turn-on Characteristics vs. Gate









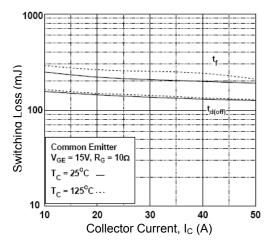


Figure 8. Turn-off Characteristics vs. Gate Resistance

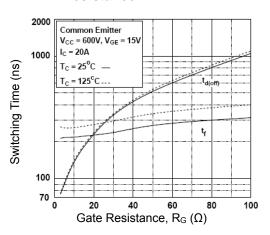
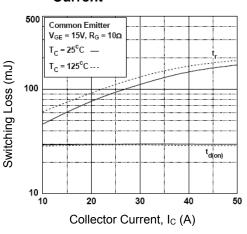
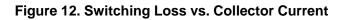
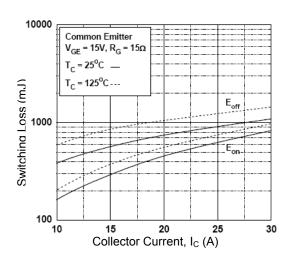


Figure 10. Turn-on Characteristics vs. Collector Current









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Typical Performance Characteristics (Continued)

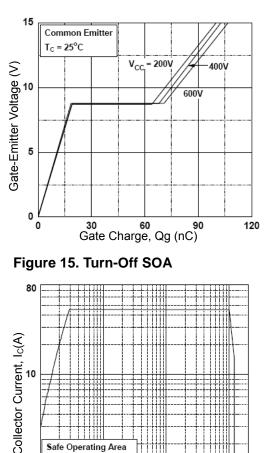


Figure13. Gate Charge Characteristics

Figure 14. SOA Characteristics

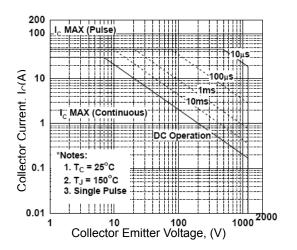
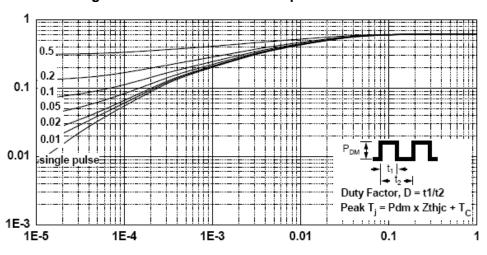


Figure 16. Transient Thermal Impedance of IGBT

1000 2000



 $V_{GE} = 15V, T_{C} = 125^{\circ}C$

10

100

Collector Emitter Voltage, (V)

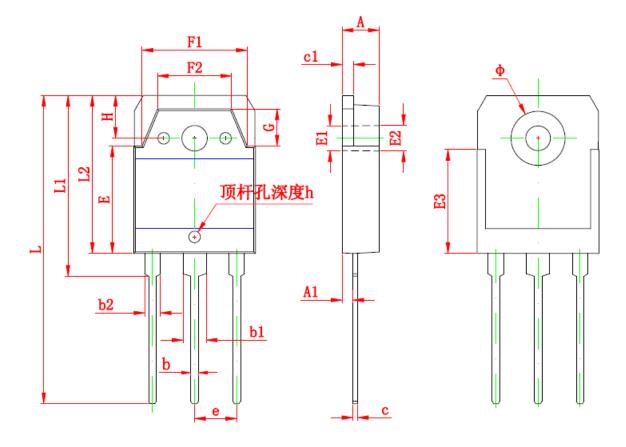
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TO-3P Mechanical Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches		
Symbol	Min	Max	Min	Max	
A	4.600	5.000	0.181	0.197	
A 1	1.200	1.600	0.047	0.063	
b	0.800	1.200	0.031	0.047	
b1	2.800	3.200	0.110	0.126	
b 2	1.800	2.200	0.071	0.087	
С	0.500	0.700	0.020	0.028	
c1	1.450	1.650	0.057	0.065	
D	15.450	15.850	0.606	0.622	
E	13.700	14.100	0.539	0.555	
E 1	3.200	REF	0.126	REF	
E 2	3.300 REF		0.130 REF		
E 3	13.45	0 REF	0.530 REF		
F 1	13.400	13.800	0.528	0.543	
F2	9.400	9.800	0.370	0.386	
L	39.900	40.300	1.571	1.587	
L1	23.200	23.600	0.913	0.929	
L2	20.300	20.600	0.799	0.811	
Ф	6.900	7.100	0.272	0.280	
G	5.150	5.550	0.203	0.219	
e	5.450 TYP		0.215 TYP		
H	5.000	REF	0.197 REF		
h	0.000	0.300	0.000	0.012	



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